RN1421TE85LF Information

For Reference Only

Part Number	RN1421TE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Description	TRANS PREBIAS NPN 200MW SMINI
Package	TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

RN1421TE85LF Specifications

Manufacturer Part Number	RN1421TE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	1k
Resistor - Emitter Base (R2) (Ohms)	1k
DC Current Gain (hFE) (Min) @ Ic, Vce	60 @ 100mA, 1V
Vce Saturation (Max) @ Ib, Ic	250mV @ 2mA, 50mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	300MHz
Power - Max	200mW
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	S-Mini

Report errors?

RN1421TE85LF Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1421TE85LF Payment Methods

RN1421TE85LF Shipping Methods

If you have any question about RN1421TE85LF, please do not hesitate to contact us!
Website: https://www.heisener.com
E-mail: salesdept@heisener.com